

Features

- 70 Watts Peak Pulse Power per Line (tp = 8/20μs)
- Bidirectional Configuration
- Protects One Power or I/O Port
- ESD Protection > 40 kilovolts
- Low Clamping Voltages



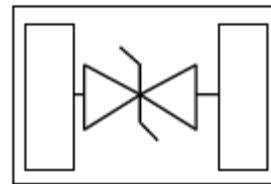
DFN1006

IEC Compatibility (EN61000-4)

- IEC 61000-4-2 (ESD) :±20kV (air), ±15kV (contact)
- IEC 61000-4-4 (EFT) :40A (5/50ns)
- IEC 61000-4-5(Surge): 4A, 8/20μs

Applications

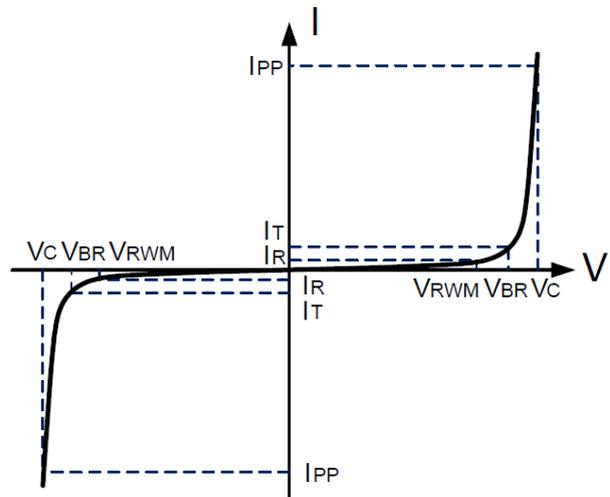
- Ethernet - 10/100/1000 Base T
- Cellular Phones
- Handheld - Wireless Systems
- Personal Digital Assistant (PDA)
- USB Interface



Electrical Parameters

Parameter	Symbol	Value	Units
Peak pulse power (tp=8/20us)	P _{PP}	70	Watts
Operating Temperature	T _J	-55°C~125°C	°C
Storage Temperature	T _{STG}	-55°C~150°C	°C

Symbol	Parameter
I _{PP}	Maximum Reverse Peak Pulse Current
V _C	Clamping Voltage @ I _{PP}
V _{RWM}	Working Peak Reverse Voltage
I _R	Maximum Reverse Leakage Current @ V _{RWM}
V _{BR}	Breakdown Voltage @ I _T
I _T	Test Current
I _F	Forward Current
V _F	Forward Voltage @ I _F

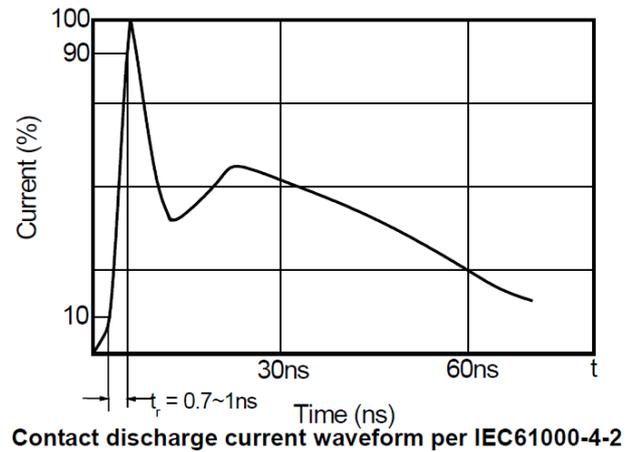
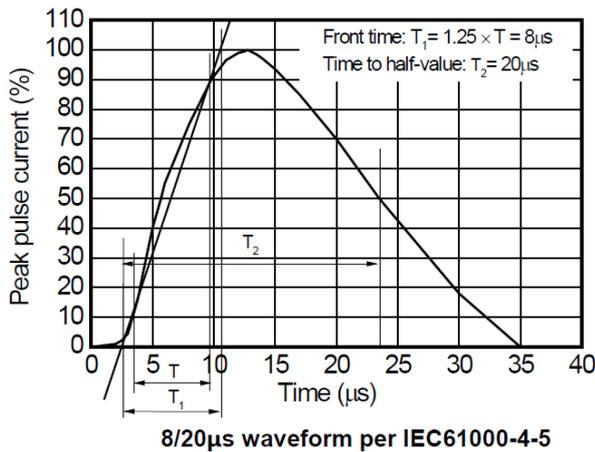


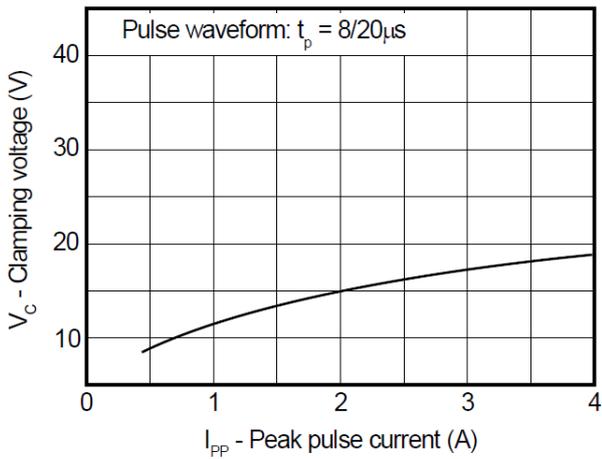
Ratings and characteristic curves ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Condition	Min	Max	Units
Reverse Stand-off Voltage	V_{RWM}	Pin2 to 1/Pin1 to 2		5.0	V
Reverse Breakdown Voltage	$V_{BR}(\text{min})$	$I_Z=1\text{mA}$	6.4	9.0	V
Reverse Leakage Current	$I_R(\text{max})$	@ V_{RWM}		0.5	μA
Clamping Voltage	V_C	$I_{PP}=4\text{A}$ $t_p=8/20\mu\text{s}$		18	V
Peak Pulse Current	I_{PP}	$t_p=8/20\mu\text{s}$	4		A
Junction Capacitance	$C_{I/O}$	Pin capacitance to GND. $V_{dc}=0\text{V}, f=1\text{MHZ}$	0.3	0.45	pf

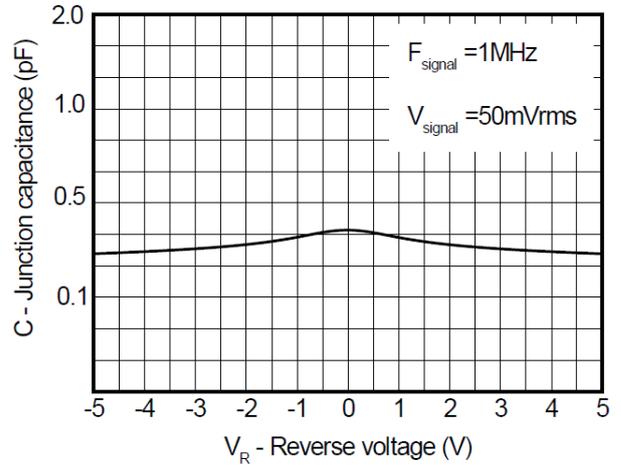
Typical Characteristics

Typical characteristics ($T_A=25^{\circ}\text{C}$, unless otherwise noted)

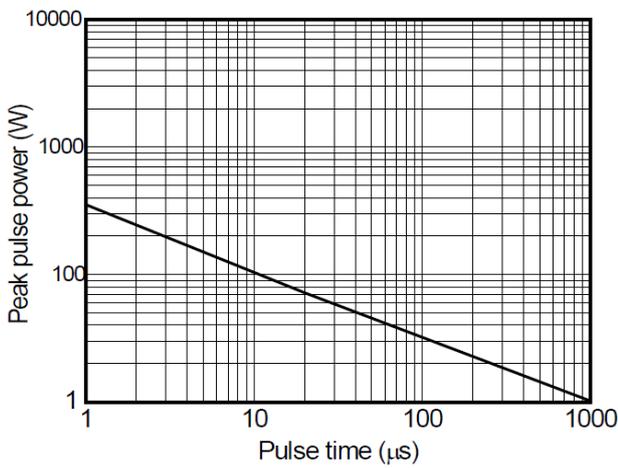




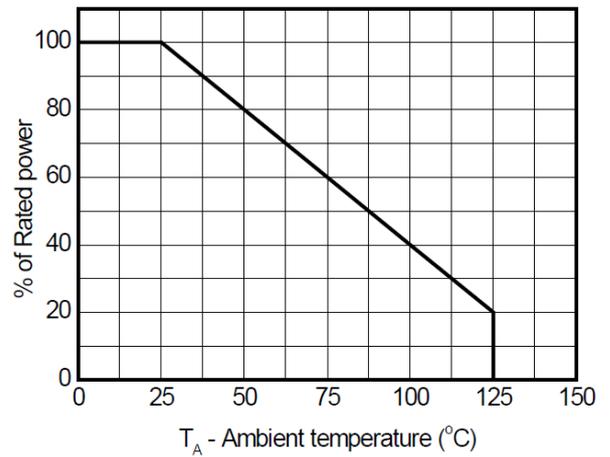
Clamping voltage vs. Peak pulse current



Capacitance vs. Reverse voltage



Non-repetitive peak pulse power vs. Pulse time



Power derating vs. Ambient temperature

Dimensions

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